

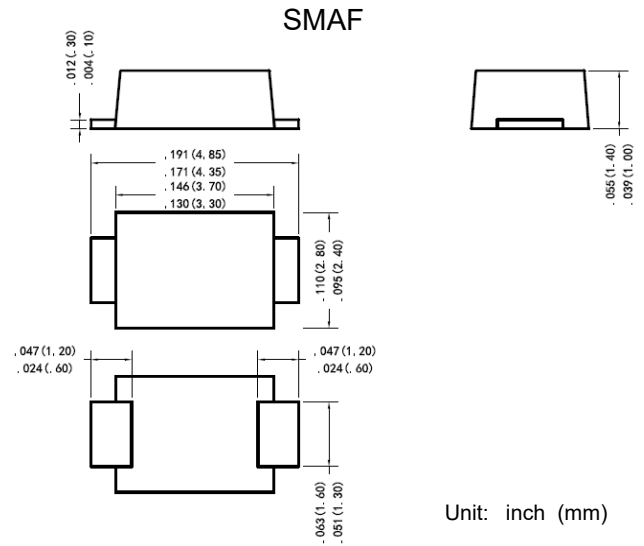
Surface Mounted Schottky Barrier Diode

Features

- Low reverse leakage
- High forward surge capability
- High reliability
- High temperature soldering guaranteed:
260°C/10seconds
- AEC-Q101 qualified
- Lead and body according with RoHS standard

Mechanical Data

- Case:SMAF Molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Pure tin plated, lead free



Maximum Ratings & Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbols	SS24AFQ	SS26AFQ	SS210AFQ	SS215AFQ	SS220AFQ	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	40	60	100	150	200	V
Maximum RMS voltage	V _{RMS}	28	42	70	105	140	V
Maximum DC blocking voltage	V _{DC}	40	60	100	150	200	V
Maximum average forward rectified current	I _{F(AV)}	2.0					A
Non-repetitive peak forward surge current 8.3 ms singlehalf sine-wave	I _{FSM}	50					A
Maximum forward voltage	V _F	0.55	0.70	0.85	0.95		V
Maximum reverse current	I _R	500		50			μA
		20		10			mA
Typical thermal resistance (Note 1)	R _{θJA}	85					°C/W
	R _{θJL}	20					
VR=4.0V,f=1MHz Type junction capacitance	C _J	120					pF
Operating junction	T _J	-55 --- +125			-55 --- +150		°C
Storage temperature rang	T _{STG}	-55 --- +150					°C

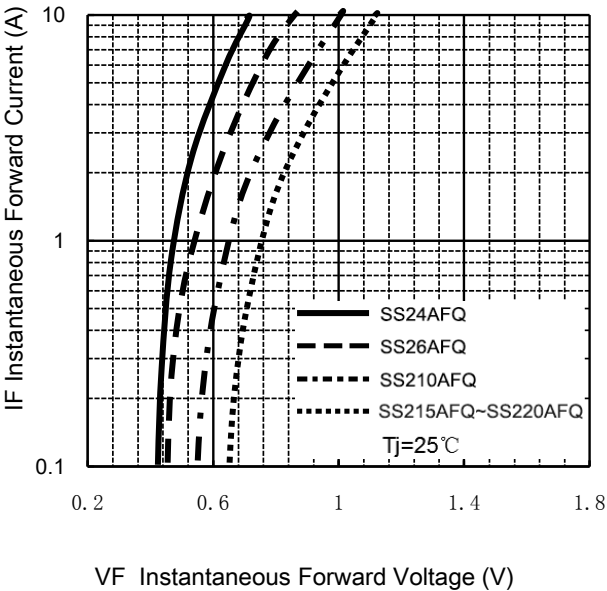
Note:

1) Thermal resistance from junction to ambient , PCB mounted.

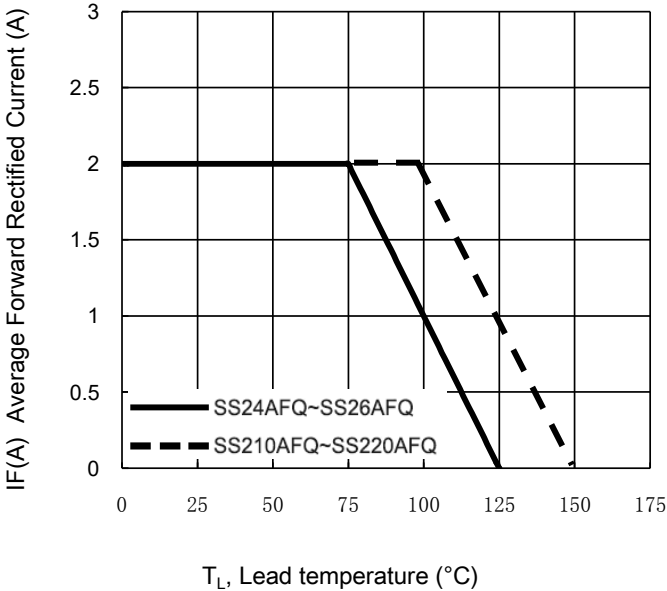


Characteristic Curves

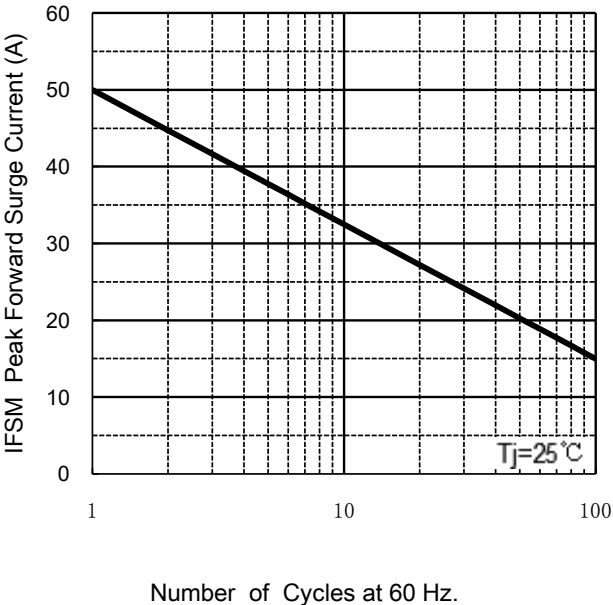
TYPICAL FORWARD CHARACTERISTIC



FORWARD CURRENT DERATING CURVE



MAXIMUM NON REPETITIVE
PEAK FORWARD SURGE CURRENT



Typical Reverse Characteristics

